MMBT6428LT1G, MMBT6429LT1G, NSVMMBT6429LT1G

Amplifier Transistors

NPN Silicon

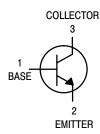
Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



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1 2

SOT-23 (TO-236) CASE 318 STYLE 6

MAXIMUM RATINGS

| Rating | Symbol | 6428LT1 | 6429LT1 | Unit |
|--------------------------------|----------------|---------|---------|------|
| Collector – Emitter Voltage | V_{CEO} | 50 | 45 | Vdc |
| Collector - Base Voltage | V_{CBO} | 60 | 55 | Vdc |
| Emitter – Base Voltage | V_{EBO} | 6.0 | | Vdc |
| Collector Current – Continuous | I _C | 200 | | mAdc |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Rating | Symbol | Value | Unit | |
|---|-----------------------------------|-------------|-------|--|
| Total Device Dissipation FR-5 Board (Note 1) $T_A = 25$ °C | P _D | 225 | mW | |
| Derate above 25°C | | 1.8 | mW/°C | |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 556 | °C/W | |
| Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C | P_{D} | 300 | mW | |
| Derate above 25°C | | 2.4 | mW/°C | |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 417 | °C/W | |
| Junction and Storage Temperature | T _J , T _{stg} | -55 to +150 | °C | |

- 1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.

MARKING DIAGRAM



XXX = Specific Device Code MMBT6428LT1 - 1KM NSV/MMBT6429LT1 - M1L

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-----------------|---------------------|-----------------------|
| MMBT6428LT1G | SOT-23 (Pb-Free) | 3000 Tape & Reel |
| MMBT6429LT1G | SOT-23 (Pb-Free) | 3000 Tape & Reel |
| NSVMMBT6429LT1G | SOT-23 (Pb-Free) | 3000 Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MMBT6428LT1G, MMBT6429LT1G, NSVMMBT6429LT1G

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Characteristic | | Symbol | Min | Max | Unit |
|---|------------------------------------|-----------------------|------------|-------------|------|
| OFF CHARACTERISTICS | | | • | | |
| Collector – Emitter Breakdown Voltage $(I_C = 1.0 \text{ mAdc}, I_B = 0)$ $(I_C = 1.0 \text{ mAdc}, I_B = 0)$ | MMBT6428 MMBT6429 / NSVMMBT6429 | V _(BR) CEO | 50 45 | - - | Vdc |
| Collector – Base Breakdown Voltage ($I_C = 0.1 \text{ mAdc}, I_E = 0$) ($I_C = 0.1 \text{ mAdc}, I_E = 0$) | MMBT6428 MMBT6429 / NSVMMBT6429 | V _{(BR)CBO} | 60 55 | - - | Vdc |
| Collector Cutoff Current (V _{CE} = 30 Vdc) | | I _{CES} | - | 0.1 | μAdc |
| Collector Cutoff Current (V _{CB} = 30 Vdc, I _E = 0) | | I _{CBO} | - | 0.01 | μAdc |
| Emitter Cutoff Current (V _{EB} = 5.0 Vdc, I _C = 0) | | I _{EBO} | - | 0.01 | μAdc |
| ON CHARACTERISTICS | | | | | |
| DC Current Gain ($I_C = 0.01 \text{ mAdc}$, $V_{CE} = 5.0 \text{ Vdc}$) | MMBT6428 MMBT6429 / NSVMMBT6429 | h _{FE} | 250 500 | - | - |
| $(I_C = 0.1 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$ | MMBT6428 MMBT6429 / NSVMMBT6429 | | 250 500 | 650 1250 | |
| $(I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$ | MMBT6428 MMBT6429 / NSVMMBT6429 | | 250 500 | - - | |
| $(I_C = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$ | MMBT6428 MMBT6429 / NSVMMBT6429 | | 250 500 | - - | |
| Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}$, $I_B = 0.5 \text{ mAdc}$) ($I_C = 100 \text{ mAdc}$, $I_B = 5.0 \text{ mAdc}$) | | V _{CE(sat)} | _ _ | 0.2 0.6 | Vdc |
| Base – Emitter On Voltage (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc) | | V _{BE(on)} | 0.56 | 0.66 | Vdc |
| SMALL-SIGNAL CHARACTERISTICS | | | | | |
| Current – Gain – Bandwidth Product (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc, f = 100 MHz) | | f _T | 100 | 700 | MHz |
| Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz) | | $C_{ m obo}$ | - | 3.0 | pF |
| Input Capacitance $(V_{EB} = 0.5 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz})$ | | C _{ibo} | - | 8.0 | pF |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

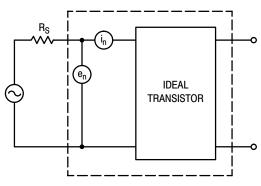


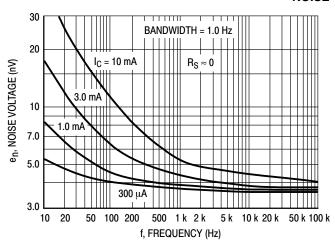
Figure 1. Transistor Noise Model

MMBT6428LT1G, MMBT6429LT1G, NSVMMBT6429LT1G

NOISE CHARACTERISTICS

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$

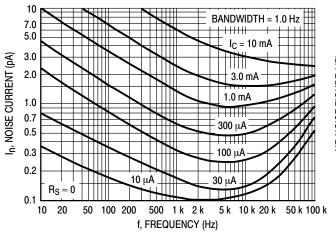
NOISE VOLTAGE



BANDWIDTH = 1.0 Hz 20 en, NOISE VOLTAGE (nV) $R_S \approx 0\,$ f = 10 Hz 10 100 Hz 7.0 1.0 kHz 5.0 3.0 0.01 0.02 0.05 0.1 0.2 0.5 1.0 5.0 10 IC, COLLECTOR CURRENT (mA)

Figure 2. Effects of Frequency

Figure 3. Effects of Collector Current



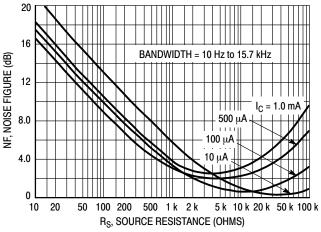
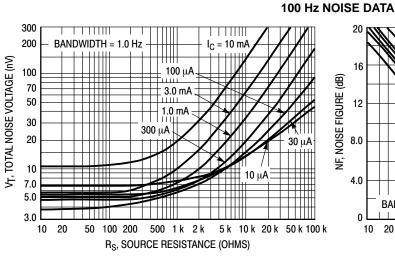


Figure 4. Noise Current

Figure 5. Wideband Noise Figure



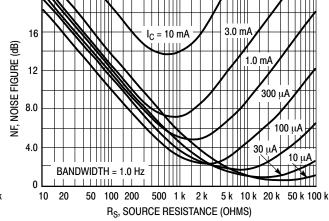


Figure 6. Total Noise Voltage

Figure 7. Noise Figure

MMBT6428LT1G, MMBT6429LT1G, NSVMMBT6429LT1G

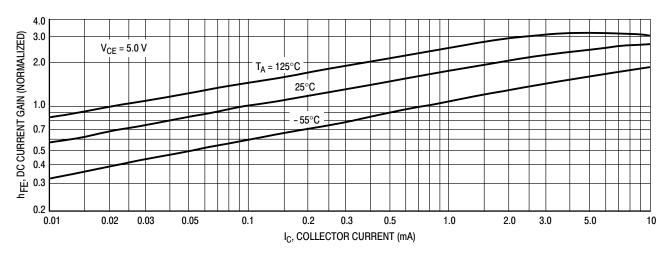


Figure 8. DC Current Gain

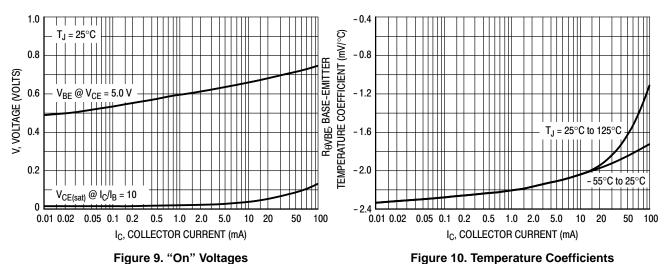


Figure 9. "On" Voltages

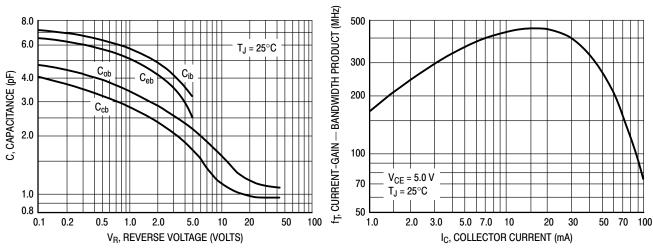


Figure 11. Capacitance

Figure 12. Current-Gain — Bandwidth Product



SOT-23 (TO-236) CASE 318-08 **ISSUE AS**

DATE 30 JAN 2018

SCALE 4:1 D - 3X b

TOP VIEW







RECOMMENDED SOLDERING FOOTPRINT



DIMENSIONS: MILLIMETERS

NOTES:

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
 MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,

| | PROT | RUSIONS, OR GATE BURRS. | |
|--|------|-------------------------|--|
|--|------|-------------------------|--|

| | MILLIMETERS | | | | INCHES | |
|-----|-------------|------|------|-------|--------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 0.89 | 1.00 | 1.11 | 0.035 | 0.039 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.017 | 0.020 |
| С | 0.08 | 0.14 | 0.20 | 0.003 | 0.006 | 0.008 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| е | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.080 |
| L | 0.30 | 0.43 | 0.55 | 0.012 | 0.017 | 0.022 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.027 |
| HE | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| Т | 0° | | 10° | 0° | | 10° |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

| STYLE 1 THRU 5: CANCELLED | STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR | STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE |
|------------------------------|---|---|--|
| OT (1 F O | | | |

SOT-23 (TO-236)

| STYLE 9: | STYLE 10: | STYLE 11: | STYLE 12: | STYLE 13: | STYLE 14: |
|---------------------------|--------------------------|---------------------------------|---------------------------|---------------|-------------------------|
| PIN 1. ANODE | PIN 1. DRAIN | PIN 1. ANODE | PIN 1. CATHODE | PIN 1. SOURCE | PIN 1. CATHODE |
| ANODE | SOURCE | CATHODE | CATHODE | 2. DRAIN | 2. GATE |
| CATHODE | 3. GATE | CATHODE-ANODE | ANODE | 3. GATE | ANODE |

| STYLE 15: | STYLE 16: | STYLE 17: | STYLE 18: | STYLE 19: | STYLE 20: |
|---------------------------|---------------------------|---------------------------|---------------------------|--------------------------------|-------------------------|
| PIN 1. GATE | PIN 1. ANODE | PIN 1. NO CONNECTION | PIN 1. NO CONNECTION | PIN 1. CATHODE | PIN 1. CATHODE |
| CATHODE | CATHODE | 2. ANODE | CATHODE | 2. ANODE | ANODE |
| ANODE | CATHODE | CATHODE | ANODE | CATHODE-ANOD | E 3. GATE |

| STYLE 21: | STYLE 22: | STYLE 23: | STYLE 24: | STYLE 25: | STYLE 26: |
|--------------------------|--------------------------|--------------|-------------|--------------|---------------------------------|
| PIN 1. GATE | PIN 1. RETURN | PIN 1. ANODE | PIN 1. GATE | PIN 1. ANODE | PIN 1. CATHODE |
| SOURCE | OUTPUT | 2. ANODE | 2. DRAIN | 2. CATHODE | 2. ANODE |
| 3 DRAIN | 3 INPLIT | 3 CATHODE | 3. SOURCE | 3. GATE | NO CONNECTION |

| STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE | STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE | |
|---|---|--|
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